

MS1409

MS1409 Information



For Reference Only

Part Number	MS1409
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF
Description	TRANS RF BIPO 7W 1A TO39
Package	TO-205AD, TO-39-3 Metal Can
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MS1409 Specifications

Manufacturer Part Number	MS1409
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	TO-205AD, TO-39-3 Metal Can
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	40V
Frequency - Transition	175MHz
Noise Figure (dB Typ @ f)	-
Gain	10dB
Power - Max	7W
DC Current Gain (hFE) (Min) @ Ic, Vce	20 @ 100mA, 5V
Current - Collector (Ic) (Max)	1A
Operating Temperature	200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-205AD, TO-39-3 Metal Can
Supplier Device Package	TO-39
	Report errors?

MS1409 Guarantees



If you have any question about MS1409, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com